

# SH7280 Group

R01AN0387EJ0100

Rev. 1.00

## Using User Program Mode

Nov. 30, 2010

### Summary

This application note describes an example to run the flash memory reprogramming program in SH7286 microcomputers (MCUs) user program mode. An external device which is connected to the SH7286 stores the data to write to the flash memory, and communicates with the flash memory using the Serial Communication Interface with FIFO.

The flash memory reprogramming program described in this application note is stored on the SH7286 user MAT. The simple flash API for SH2 and SH2A (Standard API) provided by the Renesas Electronics is used to reprogram the flash memory.

### Target Device

SH7286 MCU

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## 1. Introduction

### 1.1 Specifications

This application programs, erases, and reads the flash memory using user program mode. User program mode handles programming, erasing, and reading with a desired interface. This application uses the serial communication between the host computer and the SH7286 to handle these processing.

When the SH7286 receives the flash reprogramming/erasing command (user control command) from the host computer while executing the user application, the SH7286 programs or erases the flash memory. When it receives the flash memory reading command from the host computer, it reads the flash memory.

Figure 1 shows the system configuration of this application.

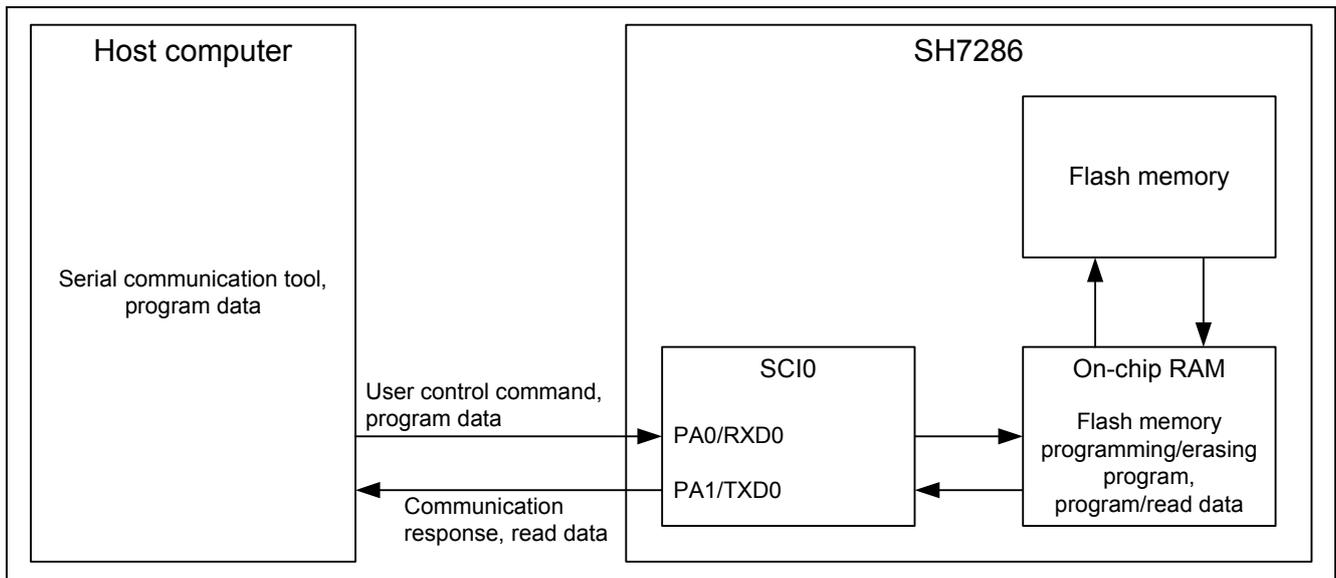


Figure 1 System Configuration

## 1.2 Modules Used

- Serial Communication Interface (SCI)
- Flash Memory (ROM)

## 1.3 Applicable Conditions

MCU	SH7286 (1-MB flash memory version)
Operating Frequency <sup>(1)</sup>	Internal clock: 25 MHz Bus clock: 25 MHz Peripheral clock: 25 MHz
Integrated Development Environment <sup>(2)</sup>	Renesas Electronics Corporation High-performance Embedded Workshop Ver.4.04.01
C Compiler	Renesas Electronics SuperH RISC engine Family C/C++ compiler package Ver.9.01 Release 01
Compiler Options	Default setting in the High-performance Embedded Workshop (-cpu=sh2a -debug -gbr=auto -global_volatile=0 -opt_range=all -infinite_loop=0 -del_vacant_loop=0 -struct_alloc=1)

Notes: 1. When downloading the on-chip program to program or erase the flash memory, set the ratio of internal clock (I $\phi$ ), bus clock (B $\phi$ ), and peripheral clock (P $\phi$ ) by the Frequency control register (FRQCR) as 1/4:1/4:1/4 to the input clock frequency.

2. As the E10A-USB emulator does not support boot mode, user boot mode, and user program mode, the flash memory reprogramming program cannot be debugged by the E10A-USB emulator.

## 1.4 Related Application Note

For more information, refer to the following application note:

- SH Family Simple Flash API for SH2 and SH2A

## 2. Overview

This application uses the Serial Communication Interface (SCI) to connect the SH7286 with the external device.

### 2.1 Overview of Modules

#### 2.1.1 Serial Communication Interface (SCI)

SCI supports both asynchronous and clocked synchronous serial communication. It also supports full-duplex communication and allows double-buffering both at transmitter and receiver to transmit/receive the serial data continuously at high speed.

This application uses the SCI for the handshake between the SH7286 and an external device, and to transmit/receive the flash memory reprogram data.

Figure 2 shows the SCI block diagram.

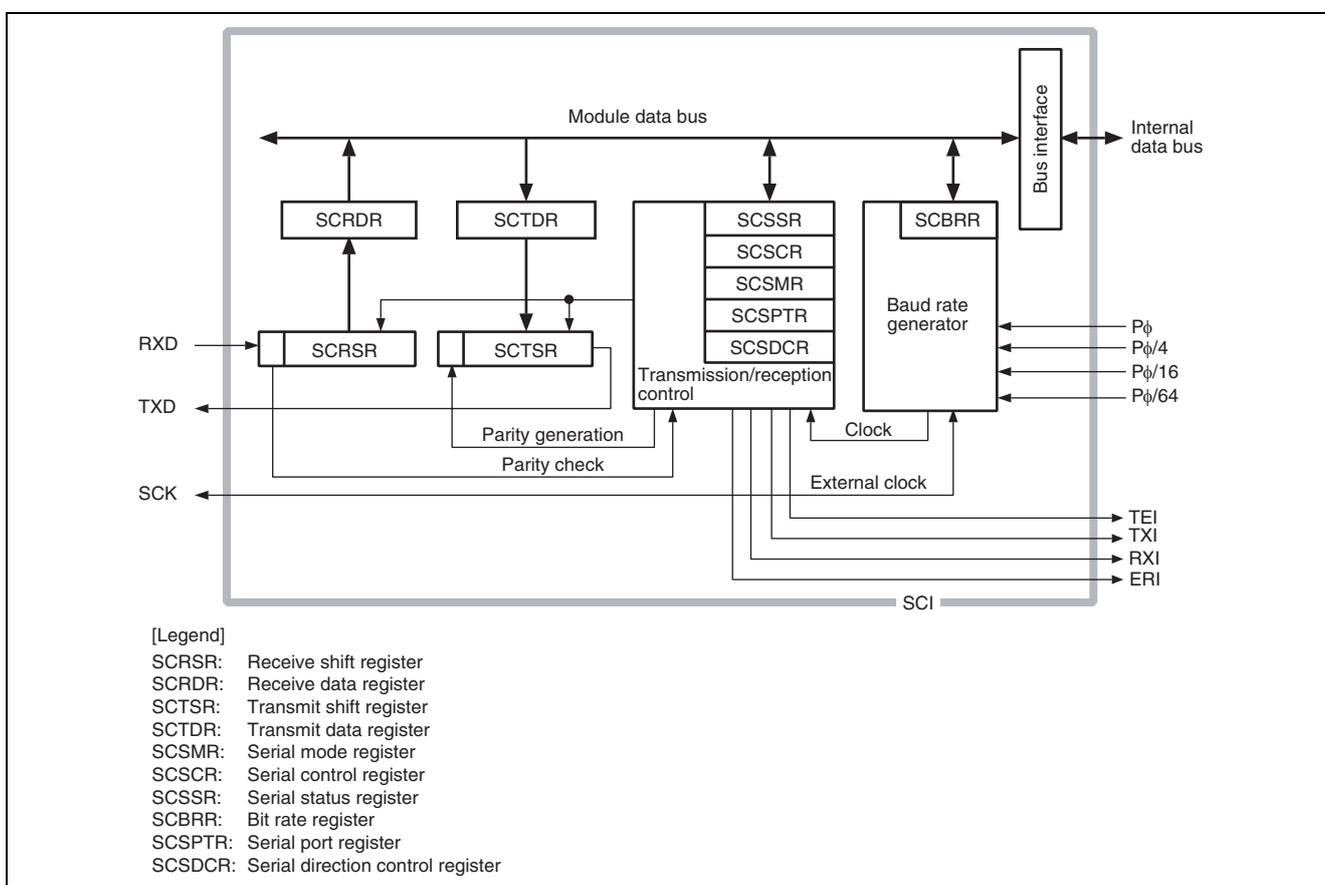
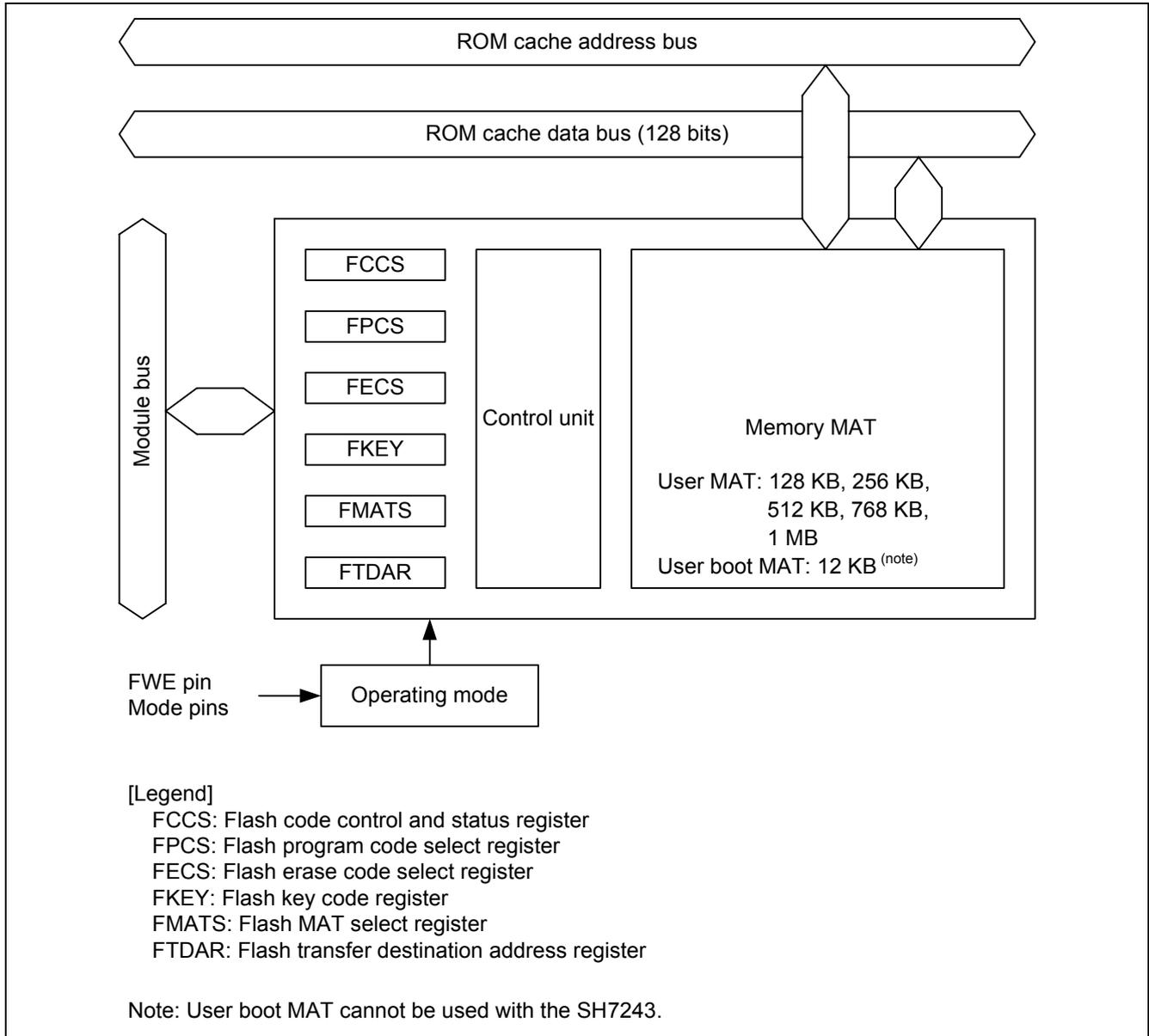


Figure 2 SCI Block Diagram

### 2.1.2 Flash Memory (ROM)

The SH7280 group MCU programs or erases the flash memory using its on-chip program.

Figure 3 shows the flash memory block diagram.



**Figure 3 Flash Memory Block Diagram**

## 2.2 Programming/Erasing the Flash Memory

The SH7280 group MCU uses its on-chip program to program and erase the flash memory. This section describes how to reprogram the flash memory. For more information, refer to the SH7280 Group Hardware Manual. This application uses the Standard API. For more information about the API, refer to the related application note.

### 2.2.1 Preparing to Program/Erase the Flash Memory

To use the MCU on-chip program, the user must download the program to the on-chip RAM. After downloading is completed, specify the program address or data, erase block to the Programming/erasing interface registers/parameters and the downloaded program programs/erases the flash memory.

User must prepare programs to request to download, program and erase the flash memory, and detect the outcome, however, the SCO bit in the FCCS register must be set in on-chip RAM. As all downloaded on-chip programs are in on-chip RAM, make sure not to use the same area in on-chip RAM.

Figure 4 shows the downloaded program area memory map.

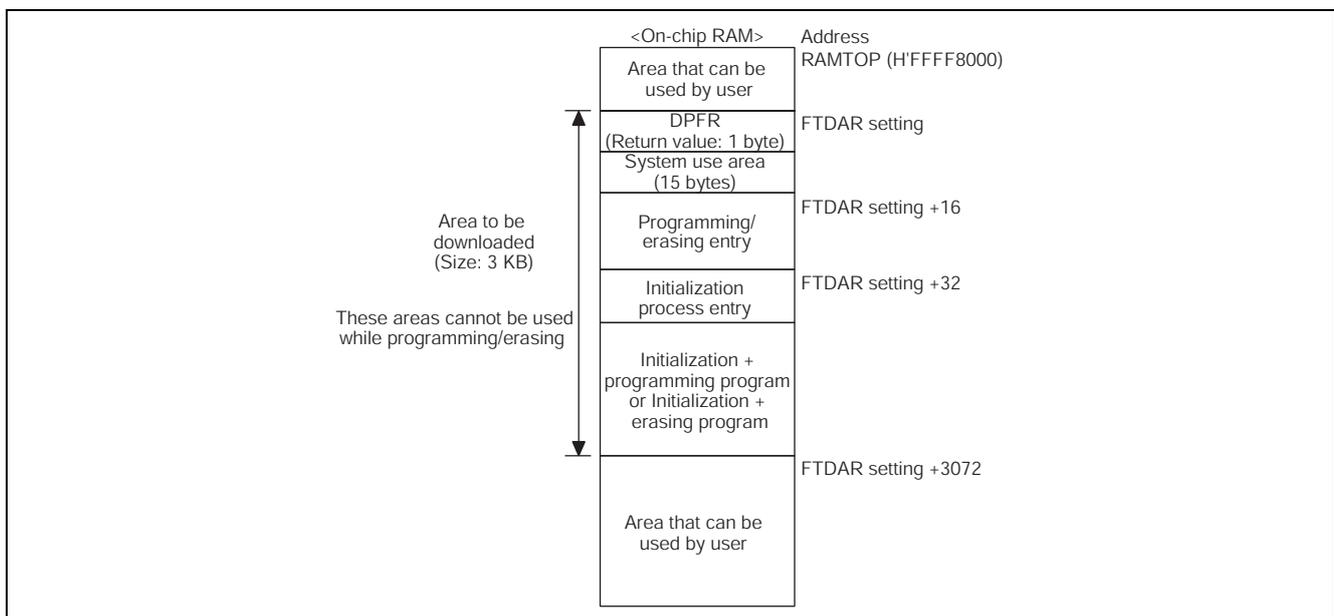
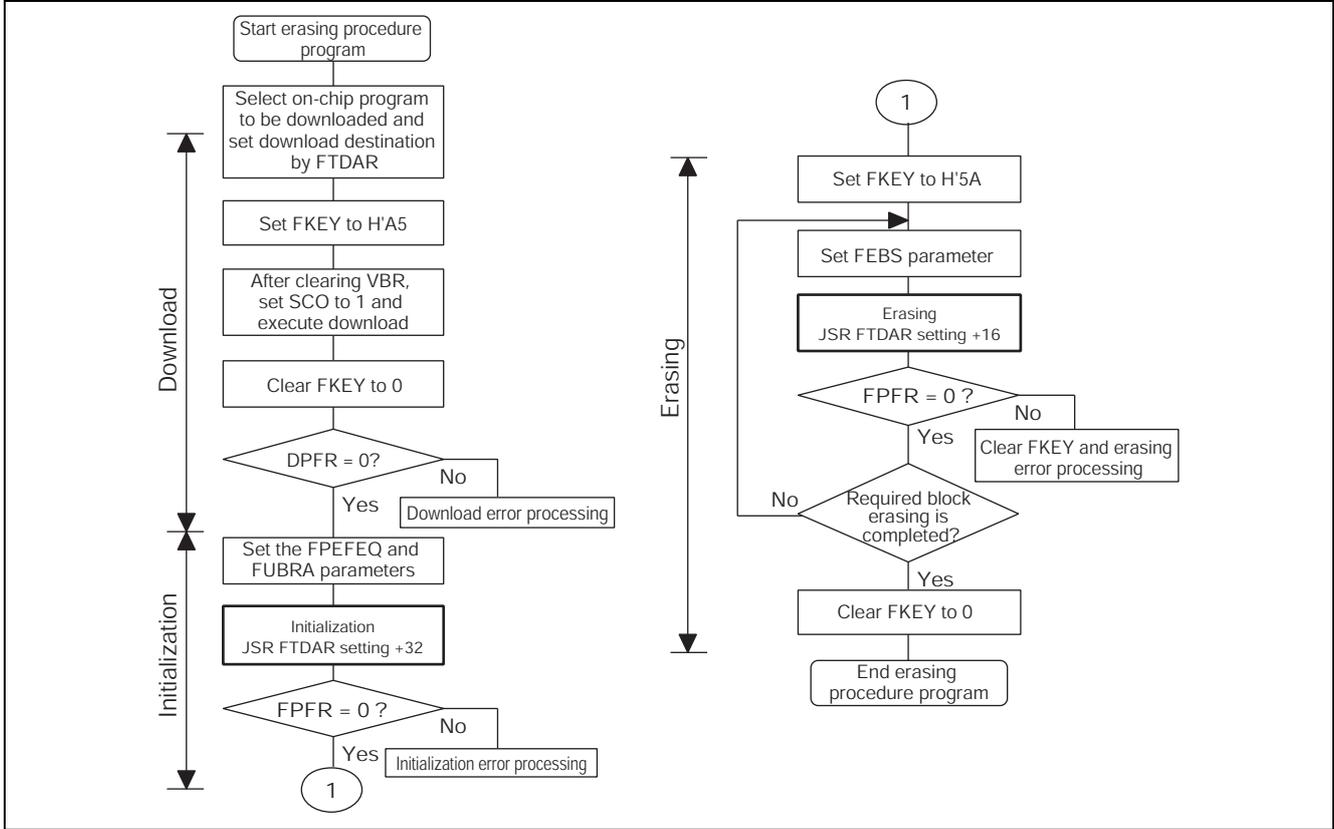


Figure 4 Memory Map After Downloading the Program

**2.2.2 Erasing the Flash Memory**

Change the download destination on-chip RAM address in the FTDAR register to download the erasing program and programming program in other on-chip RAM areas separately.

Figure 5 shows the flow chart for erasing the flash memory.



**Figure 5 Erasing the Flash Memory**

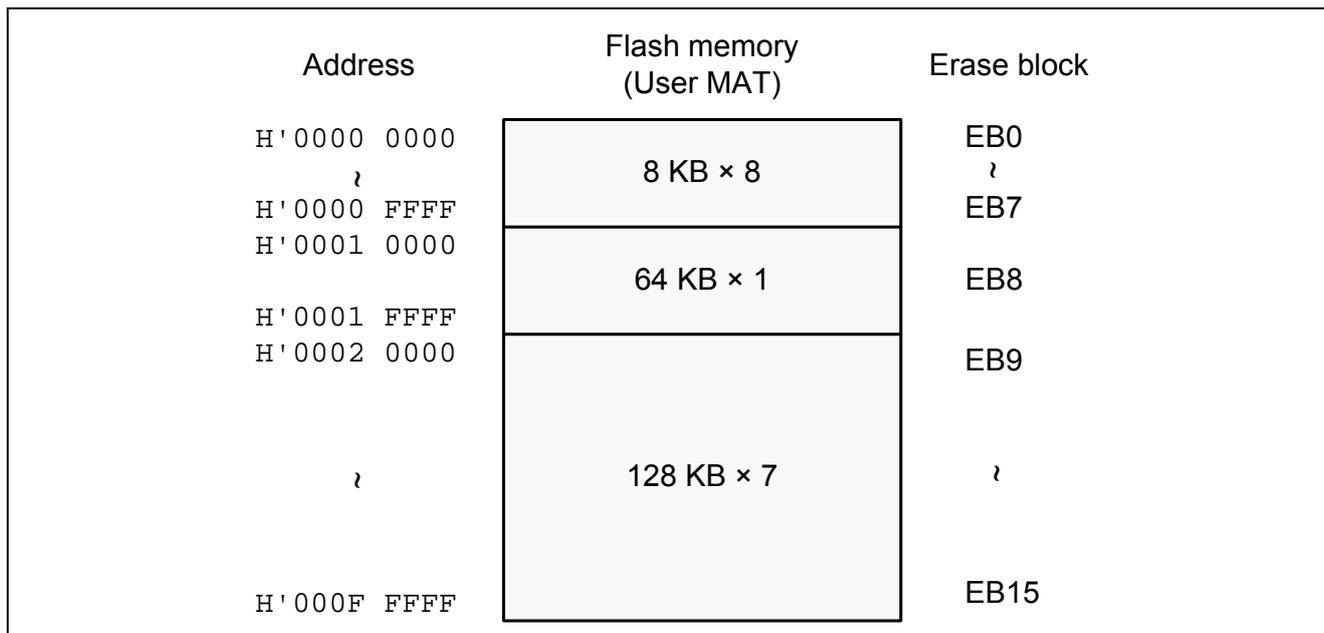


Figure 6 Dividing the Flash Memory Erase Block

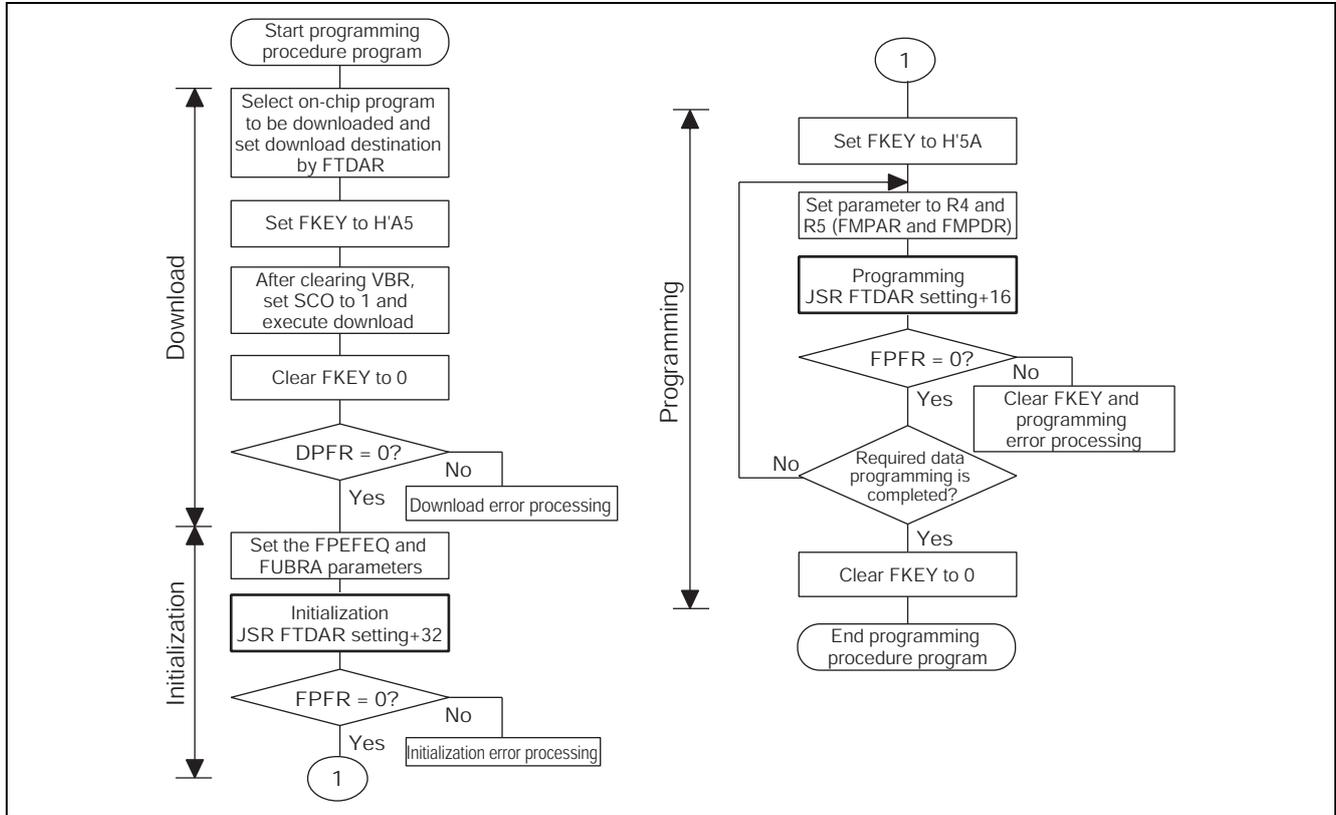
Table 1 Erase Block and Address

Erase Block	Address	Capacity
EB0	H'0000_0000 to H'0000_1FFF	8 KB
EB1	H'0000_2000 to H'0000_3FFF	
EB2	H'0000_4000 to H'0000_5FFF	
EB3	H'0000_6000 to H'0000_7FFF	
EB4	H'0000_8000 to H'0000_9FFF	
EB5	H'0000_A000 to H'0000_BFFF	
EB6	H'0000_C000 to H'0000_DFFF	
EB7	H'0000_E000 to H'0000_FFFF	
EB8	H'0001_0000 to H'0001_FFFF	64 KB
EB9	H'0002_0000 to H'0003_FFFF	128 KB
EB10	H'0004_0000 to H'0005_FFFF	
EB11	H'0006_0000 to H'0007_FFFF	
EB12	H'0008_0000 to H'0009_FFFF	
EB13	H'000A_0000 to H'000B_FFFF	
EB14	H'000C_0000 to H'000D_FFFF	
EB15	H'000E_0000 to H'000F_FFFF	

**2.2.3 Programming the Flash Memory**

Change the download destination on-chip RAM address in the FTDAR register to download the erasing program and programming program in other on-chip RAM areas separately.

Figure 7 shows the flow chart for programming the flash memory.



**Figure 7 Programming the Flash Memory**

### 2.3 Flash Program Data Buffer

This application has the buffer area to hold the program data in the SH7286 on-chip RAM. The capacity of the buffer area is 256 bytes, which is equivalent to a flash programming.

Figure 8 shows the operation image of the buffer. Table 2 lists the data buffer area address <sup>(note)</sup>.

Note: Data buffer area is divided into sections. Change the section allocation address to set the desired buffer area address. Make sure not to use the same area as the on-chip program in on-chip RAM.

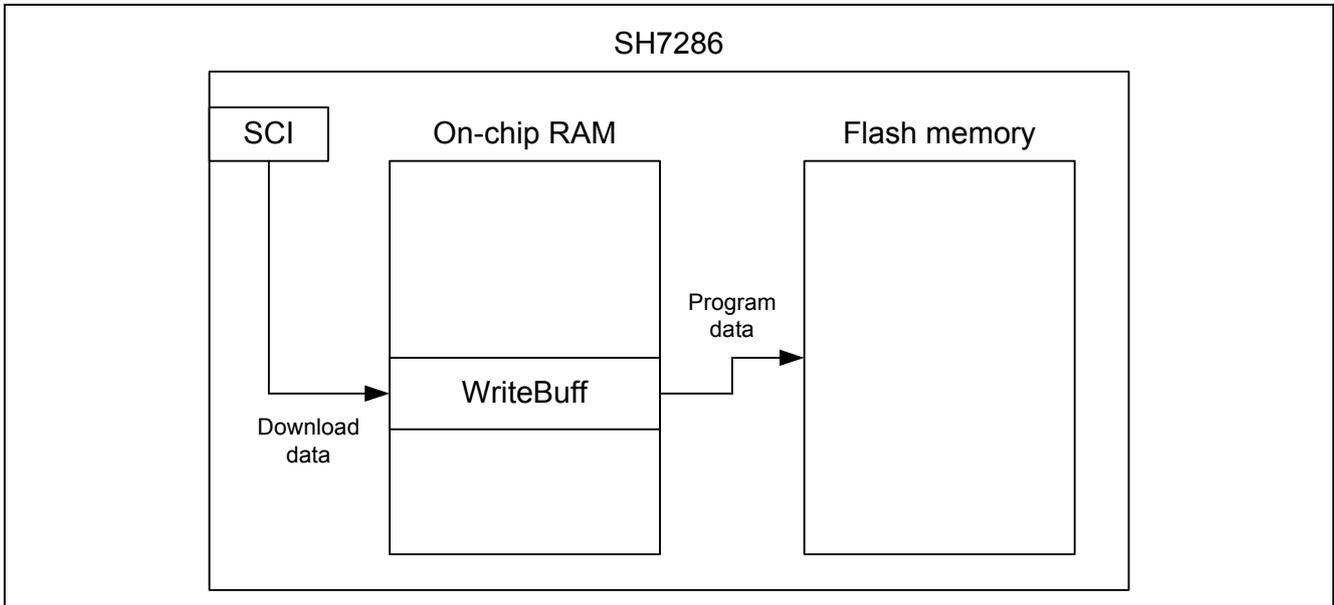


Figure 8 Buffer Operating Image

Table 2 Data Buffer Area Address

Buffer Name	Address	Capacity
WriteBuff	H'FFF8_5000 to H'FFF8_50FF	256 bytes

### 3. Sample Program External Specifications

This application allocates the flash memory reprogramming sample program including main function (sample program) in EB0 block in the user MAT (address: H'0000 0000 to H'0000 1FFF). Sample program consists of the user application (main function), serial communication program, flash memory reprogramming program, and Standard API.

The target area to program or erase in the flash memory is the user MAT (EB1 to EB15 block address: H'0000 2000 to H'000F FFFF) other than EB0 block where the sample program is allocated.

Figure 9 shows the image of programming and erasing the flash memory by the sample program.

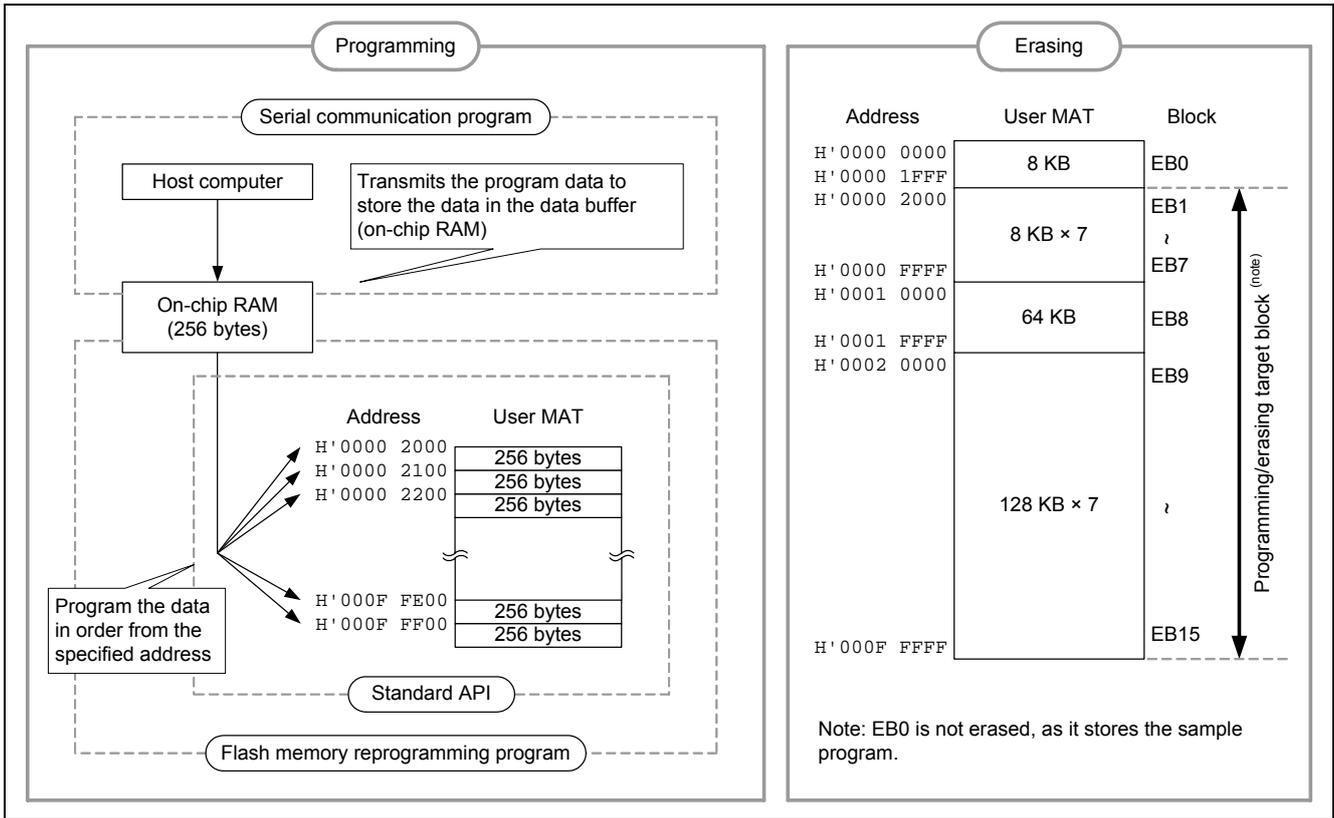


Figure 9 Programming and Erasing the Flash Memory

### 3.1 Sample Program Operation

This application executes the serial communication with the host computer and transmits/receives the user control commands for communication and data to program, erase and read the flash memory. It uses SCI channel 0 (SCI0) for the serial communication. The sample program these processing to control the flash memory in on-chip RAM.

The sample program checks whether the flash memory is program-/erase-enabled or not. When the flash memory is program-/erase-enabled, the sample program requests the host computer to issue the user control command for communication; otherwise, the sample program polls the FWE bit until the flash memory is program-/erase-enabled.

Figure 10 shows the main processing flow chart.

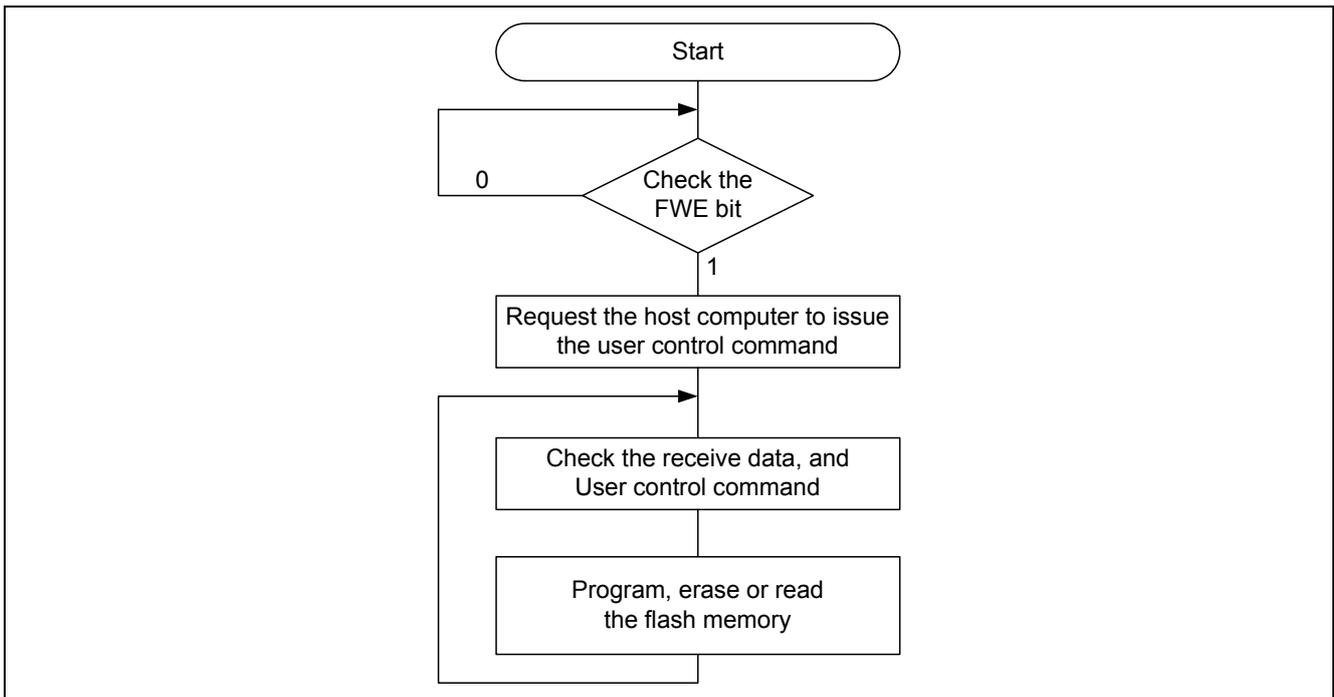


Figure 10 Main Processing Flow Chart

Table 3 lists the user control commands for communication from the host computer. Table 4 lists the notification from the SH7286.

When an error occurs while programming or erasing the flash memory, the sample program notifies the error end (RET\_NG) to the host computer and enters an infinite loop. Add the error processing as appropriate.

**Table 3 User Control Commands from the Host Computer to SH7286**

Command Name	Value	Description
CMD_GO	H'55	Starts programming/erasing the flash memory
CMD_READ	H'AA	Reads the flash memory
CMD_ERASE	H'77	Erases the flash memory
CMD_WRITE	H'88	Programs the flash memory
CMD_WEND	H'99	Ends programming/erasing the flash memory

**Table 4 Notifications from the SH7286 to the Host Computer**

Notification Name	Value	Description
Normal end (RET_OK)	H'00	Notifies the host computer that the command handling ends successfully
Error end (RET_NG)	H'01	Notifies the host computer that the command handling ends in error
Transmit request (RET_REQ)	H'11	Notifies the host computer that the sample program is requesting to transmit the user control command or the program data

### 3.1.1 Programming or Erasing the Flash Memory

When the host computer transmits the flash memory programming/erasing start command (CMD\_GO), the sample program transitions to the flash memory programming/erasing state, and notifies the transmission request (RET\_REQ) to the host computer.

Next, the host computer transmits the flash memory erasing command (CMD\_ERASE), and specifies the program/erase destination block number (other than EB0) in units of 2 bytes. This 2-byte data must be set to 1 to the bit that indicates the specified block number (i.e. Set the data to H'0002 for programming EB1, to H'0800 for programming EB11.)

When the specified block does not exist (H'0000 is specified), or bit 0 corresponding to EB0 is set to 1, the sample program notifies the error end (RET\_NG) to the host computer, and enters an infinite loop. When erasing the flash memory in the specified block is completed, the sample program notifies the normal end (RET\_OK) to the host computer.

Then, the host computer transmits the flash memory programming command (CMD\_WRITE), and the destination start address and program data size (4-byte data). Make sure to specify the address (H'0000 2000 to H'000F FFFF) within the specified block (EB1 to EB15) when erasing the flash memory at 256-byte boundary. Otherwise, the operation is not guaranteed.

When the host computer transmits the destination start address and program data size, the sample program notifies the host computer to request transmitting the program data (RET\_REQ), and the host computer transmits the program data size data. As the program data in the user MAT must be in units of 256 bytes, the sample program programs the flash memory at every 256-byte data is received. (When the specified program data size is less than 256 bytes, the sample program sets the remaining data to H'FF.)

When the total number of programming the flash memory does not reach the program data size, the sample program notifies the host computer to request transmitting (RET\_REQ) the program data. The host computer must repeat transmitting data until the size reaches the program data size. When the total number of programming the flash memory reaches the program data size, the sample program notifies the normal end (RET\_OK) to the host computer.

Finally, the host computer transmits the flash memory programming/erasing end command (CMD\_WEND), and the sample program ends programming or erasing the flash memory.

Figure 11 shows the communication command sequence when programming or erasing the flash memory by the sample program.

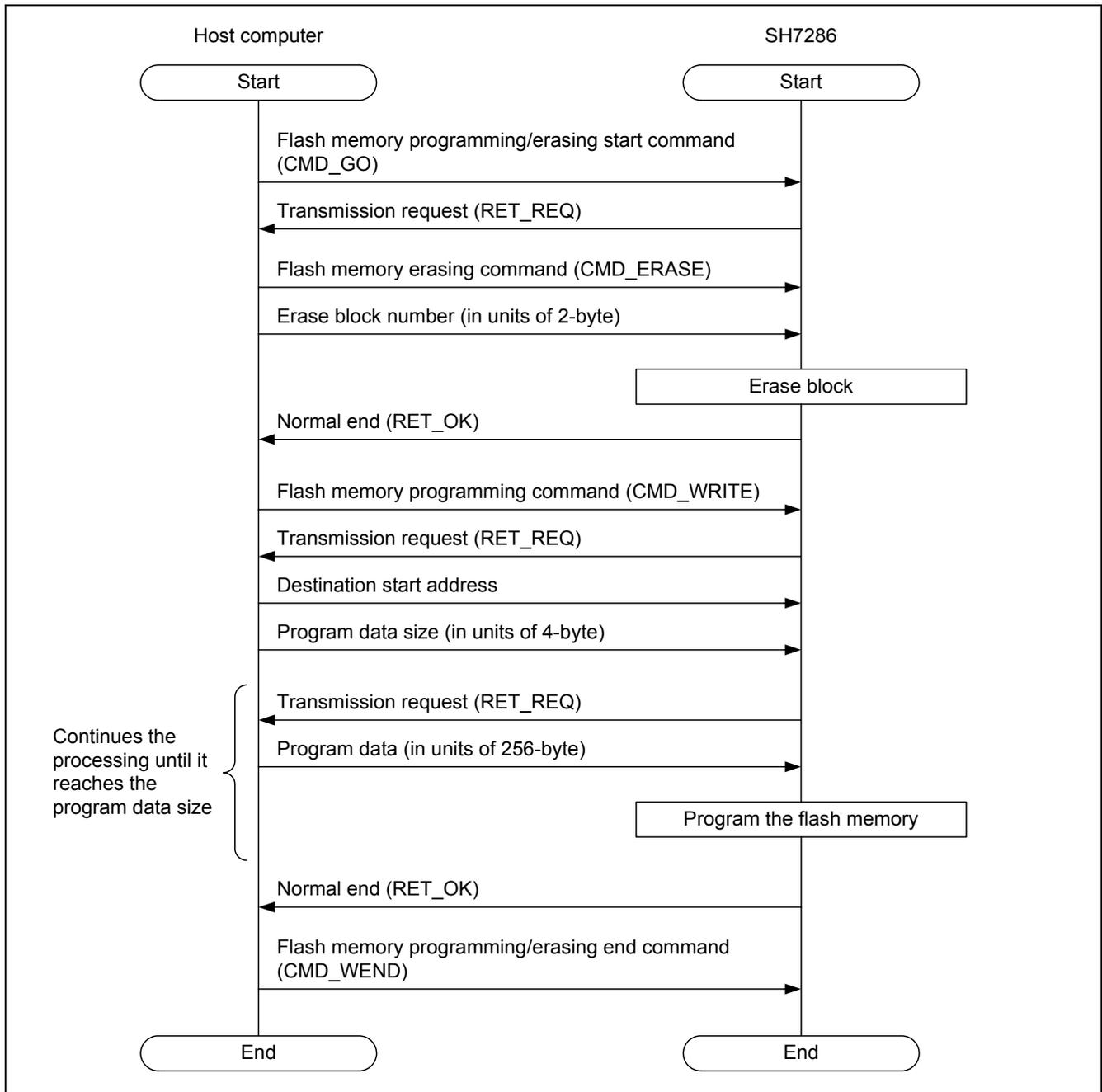


Figure 11 Communication Command Sequence When Programming/Erasing the Flash Memory

### 3.1.2 Reading the Flash Memory

The sample program reads the specified size of data from the destination start address and transmits the data to the host computer by the flash memory reading command (CMD\_READ).

When the sample program receives the flash memory reading command (CMD\_READ), it notifies the transmission request (RET\_REQ) to the host computer. When the sample program receives the destination start address (in units of 4-byte) and read data size (in units of 4-byte) from the host computer (8 bytes in total), it reads the specified size of data from the destination address, and transmits the data to the host computer.

Specify the address (H'0000 0000 to H'000F FFFF) within blocks EB0 to EB15 (User MAT) as the read destination start address. Otherwise, the sample program does not read the flash memory, notifies the error end (RET\_NG) to the host computer to enter an infinite loop. As the sample program does not include the error check when the specified address is not on the user MAT, do not specify the address that is out of bounds.

Figure 12 shows the communication command sequence when reading the flash memory.

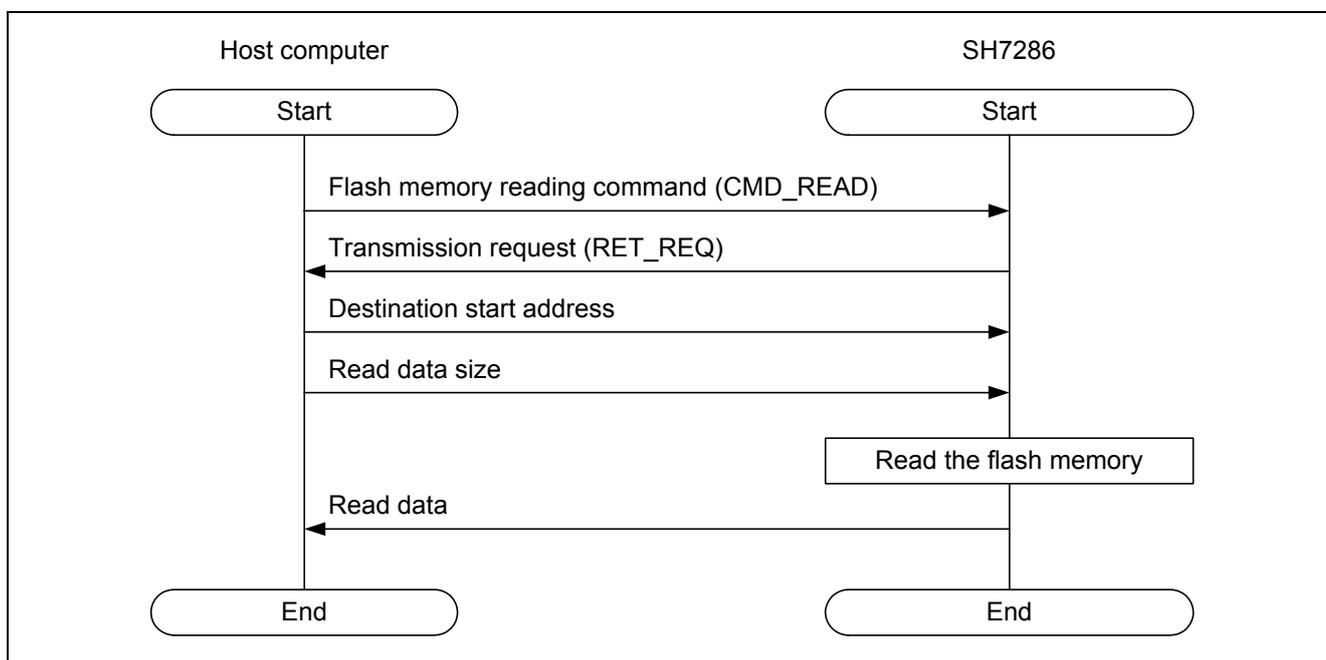


Figure 12 Communication Command Sequence When Reading the Flash Memory

## 4. Sample Program Internal Specifications

### 4.1 Modules

Table 5 lists the specifications of sample program modules.

**Table 5 Sample Program Modules**

Type	Module Name	Function Name	Description	Flow Chart
User application	Main processing	main	Executes the user application	See Figure 13
Flash memory reprogramming	Flash memory programming/erasing	ocf_write	Programs or erasing the flash memory	See Figure 14 and Figure 15
	Flash memory reading	ocf_read	Reads the flash memory	See Figure 16
	Flash memory program-/erase-enabled check	ocf_pe_chk	Checks that the flash memory is program-/erase-enabled	See Figure 17
Serial communication control	SCI configuration	io_sci_init	Configures the SCI (channel 0)	–
	SCI receive data existence check	io_sci_chk_rcv	Checks if the receive data is stored in the SCRDR register	–
	SCI transmit	io_sci_snd	Transmits one-byte data	–
	SCI receive	io_sci_rcv	Receives the specified bytes of data	–
	SCI module stop	io_sci_stop	Stop supplying the clock to the SCI (channel 0)	–
Standard API	Block erase	R_FlashErase	Erases the data in the specified block	–
	Flash memory programming	R_FlashWrite	Programs the data in the specified address	–

### 4.2 Variable Used

Table 6 lists a variable used in the sample program.

**Table 6 Variable**

Variable Label Name	Description	Module to Use
unsigned char WriteBuff[256]	Stores the program data	ocf_write

### 4.3 Register Settings

Table 7 lists the register settings for the peripherals.

**Table 7 Register Settings in the Sample Program**

Register Name	Address	Setting	Description
Frequency control register (FRQCR)	H'FFFE 0010	H'0333	<ul style="list-style-type: none"> <li>STC [2:0] = "B'011": Bus clock division ratio = 1/4</li> <li>IFC [2:0] = "B'011": Internal clock division ratio = 1/4</li> <li>PFC [2:0] = "B'011": Peripheral clock division ratio = 1/4</li> </ul>
Standby control register 5 (STBCR5)	H'FFFE 0418	H'7F	MSTP57 = "0": SCI0 is operating
Serial mode register_0 (SCSMR_0)	H'FFFF 8000	H'00	<ul style="list-style-type: none"> <li>C/A# = "0": Asynchronous mode</li> <li>CHR = "0": 8-bit data</li> <li>PE = "0": Disables to add and check the parity bit</li> <li>STOP = "0": 1 stop bit</li> <li>MP = "0": Disables the multiprocessor mode</li> <li>CKS [1:0] = "B'00": Peripheral clock</li> </ul>
Bit rate register_0 (SCBRR_0)	H'FFFF 8002	D'80	Bit rate = 9600 bps (Peripheral clock = 25 MHz)
Serial control register_0 (SCSCR_0)	H'FFFF 8004	H'30	<ul style="list-style-type: none"> <li>TE = "1": Enables the transmitter</li> <li>RE = "1": Enables the receiver</li> </ul>
Port A control register L1 (PACRL1)	H'FFFE 3816	H'0055	<ul style="list-style-type: none"> <li>PA1MD [2:0] = "B'101": Outputs TXD0 (SCI0)</li> <li>PA0MD [2:0] = "B'101": Inputs RXD0 (SCI0)</li> </ul>

4.4 Flow Charts

This section describes the flow charts of the sample program.

4.4.1 Main Flow Chart

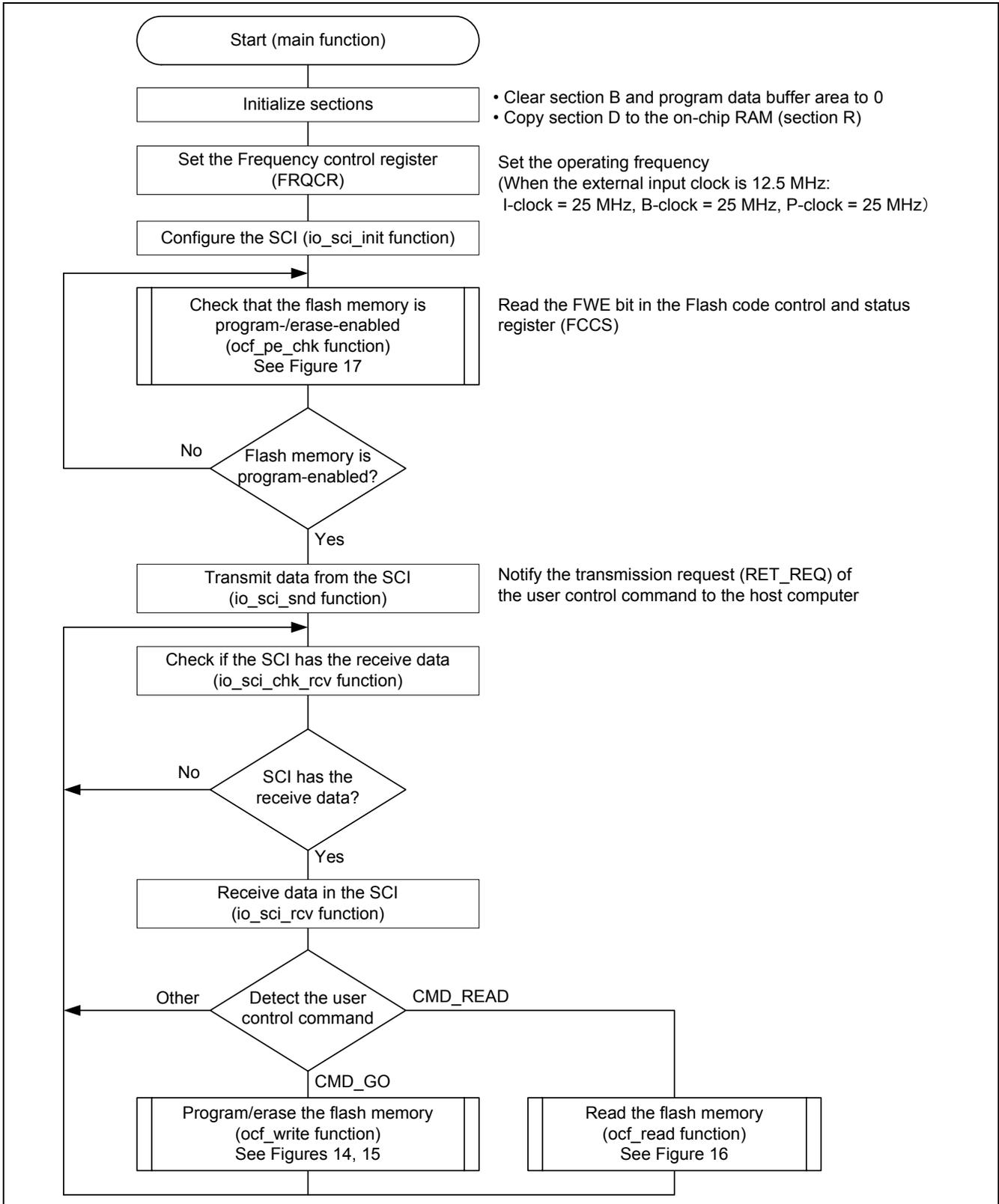


Figure 13 Main Processing Flow Chart

4.4.2 Programming/Erasing the Flash Memory

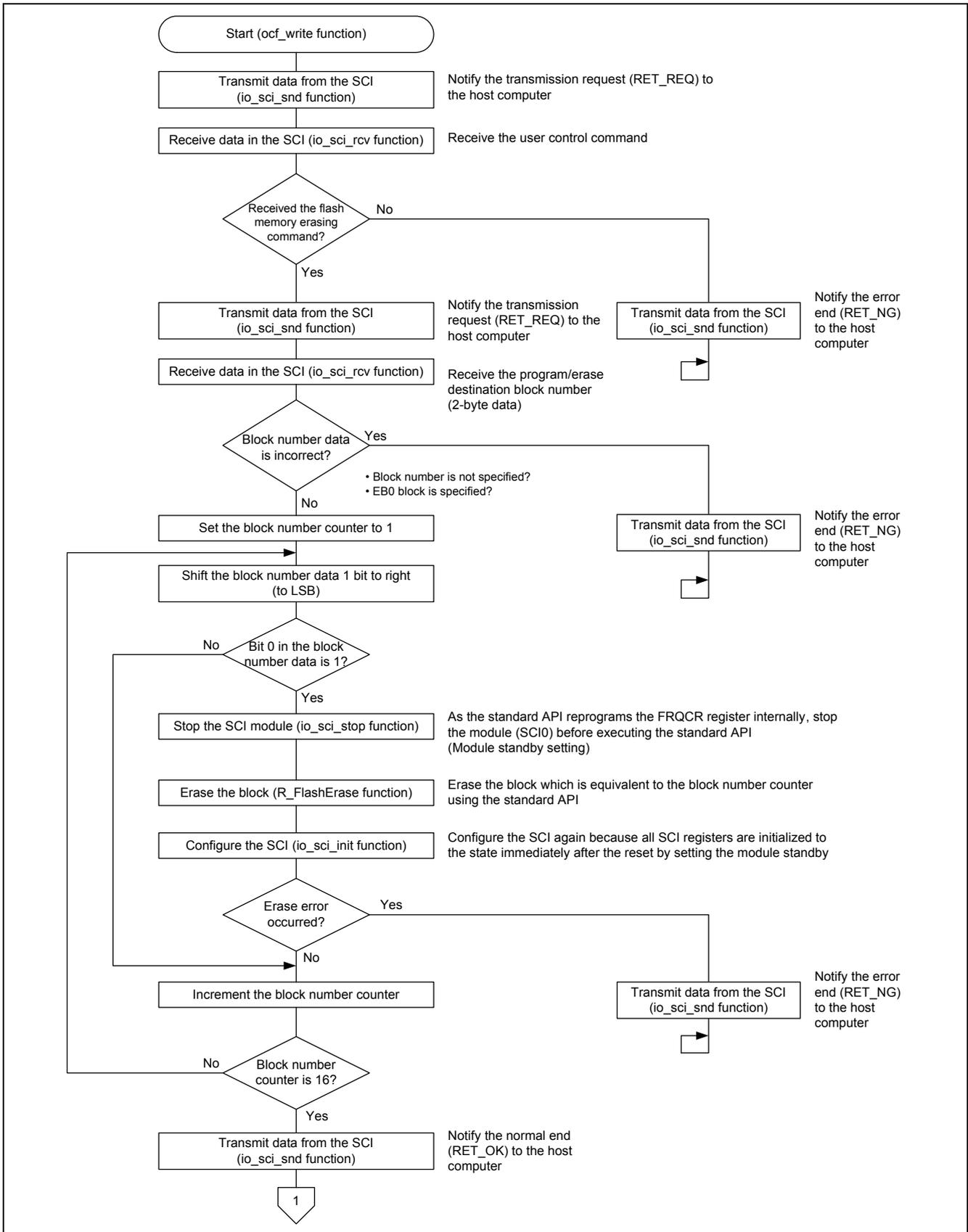


Figure 14 Programming/Erasing the Flash Memory (1/2)

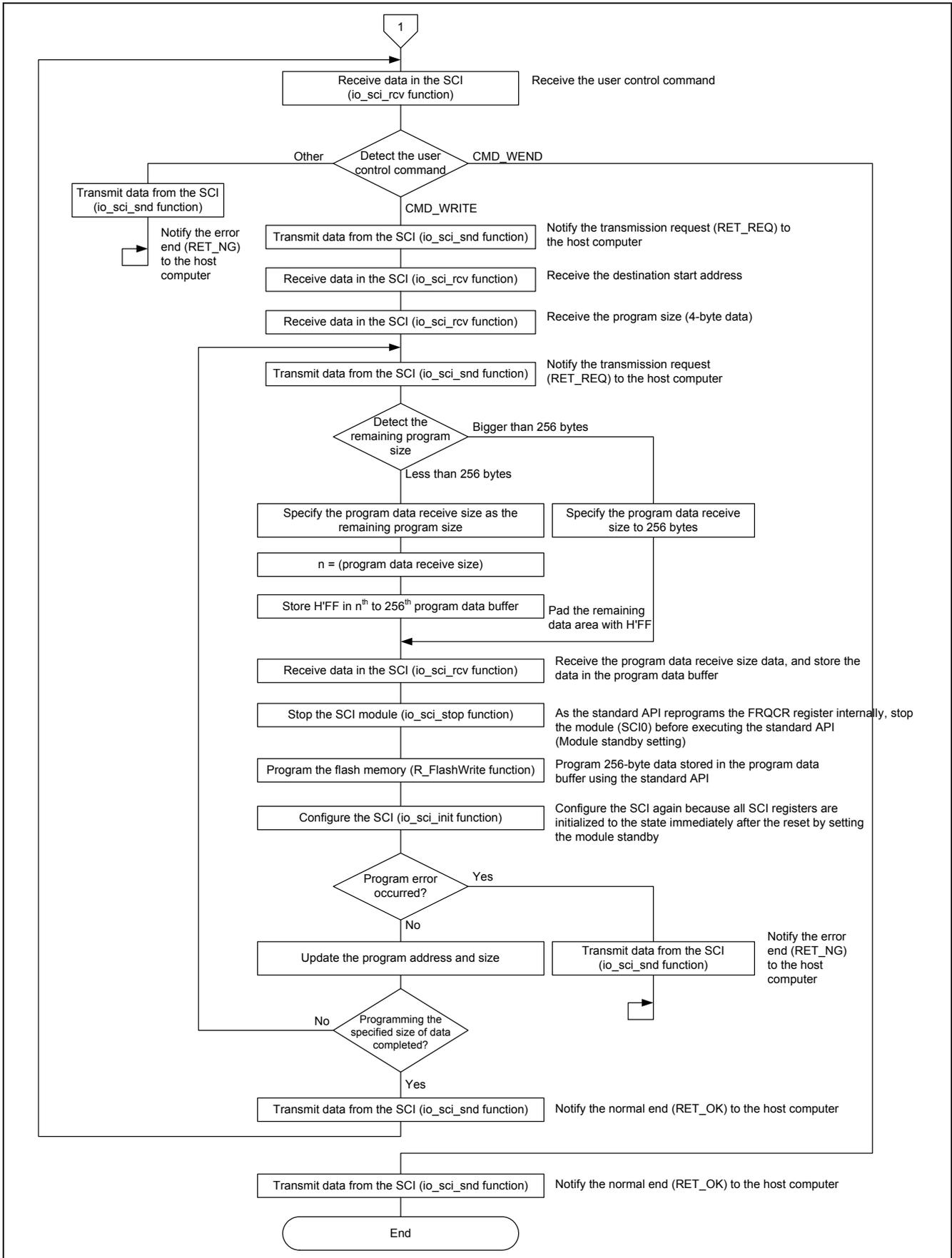


Figure 15 Programming/Erasing the Flash Memory (2/2)

4.4.3 Reading the Flash Memory

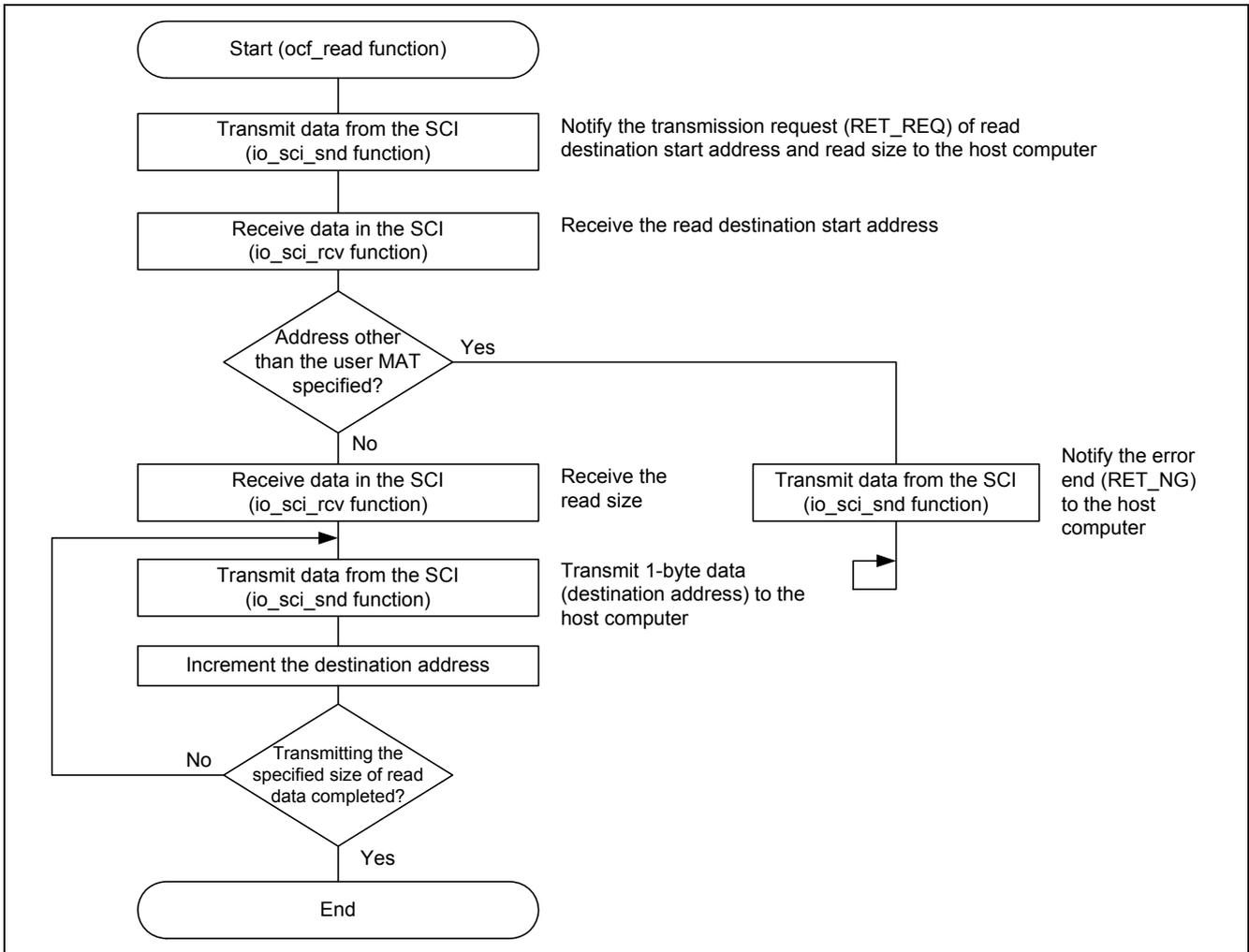


Figure 16 Reading the Flash Memory

4.4.4 Checking the Flash Memory is Program-/Erase-enabled

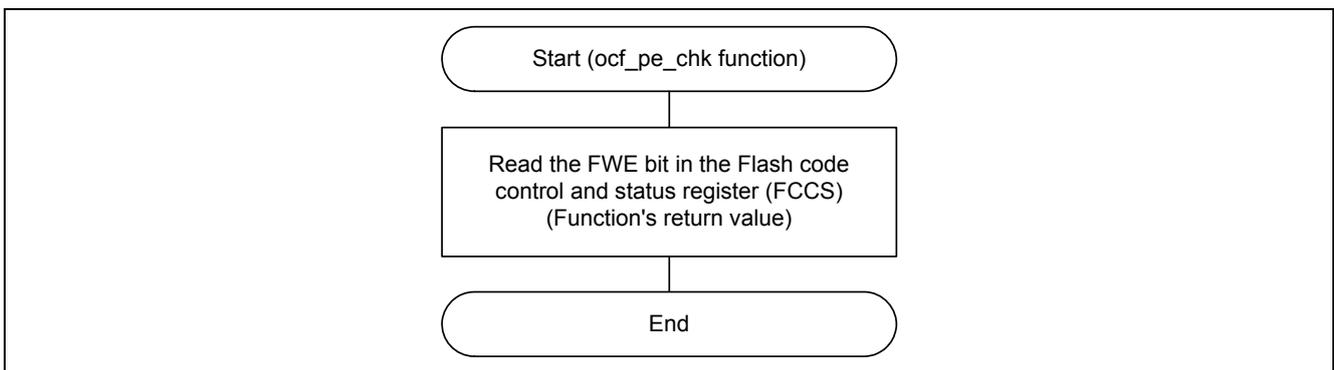


Figure 17 Checking the Flash Memory is Program-/Erase-enabled

## 5. Sample Program Listing

### 5.1 Sample Program Listing "main.c" (1/10)

```

1  /*****
2  *   DISCLAIMER
3  *
4  *   This software is supplied by Renesas Electronics Corp. and is only
5  *   intended for use with Renesas products.  No other uses are authorized.
6  *
7  *   This software is owned by Renesas Electronics Corp. and is protected under
8  *   all applicable laws, including copyright laws.
9  *
10 *   THIS SOFTWARE IS PROVIDED "AS IS" AND RENESAS MAKES NO WARRANTIES
11 *   REGARDING THIS SOFTWARE, WHETHER EXPRESS, IMPLIED OR STATUTORY,
12 *   INCLUDING BUT NOT LIMITED TO WARRANTIES OF MERCHANTABILITY, FITNESS FOR A
13 *   PARTICULAR PURPOSE AND NON-INFRINGEMENT.  ALL SUCH WARRANTIES ARE EXPRESSLY
14 *   DISCLAIMED.
15 *
16 *   TO THE MAXIMUM EXTENT PERMITTED NOT PROHIBITED BY LAW, NEITHER RENESAS
17 *   ELECTRONICS CORP. NOR ANY OF ITS AFFILIATED COMPANIES SHALL BE LIABLE
18 *   FOR ANY DIRECT, INDIRECT, SPECIAL, INCIDENTAL OR CONSEQUENTIAL DAMAGES
19 *   FOR ANY REASON RELATED TO THIS SOFTWARE, EVEN IF RENESAS OR ITS
20 *   AFFILIATES HAVE BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.
21 *
22 *   Renesas reserves the right, without notice, to make changes to this
23 *   software and to discontinue the availability of this software.
24 *   By using this software, you agree to the additional terms and
25 *   conditions found by accessing the following link:
26 *   http://www.renesas.com/disclaimer
27 *****/
28 *   Copyright (C) 2010 Renesas Electronics Corporation. All rights reserved.
29 *****/
30 /*"FILE COMMENT"***** Technical reference data *****/
31 *   System Name : SH7286 Sample Program
32 *   File Name   : main.c
33 *   Abstract    : Using user program mode
34 *   Version     : 1.00.00
35 *   Device      : SH7286
36 *   Tool-Chain  : High-performance Embedded Workshop (Ver.4.04.01).
37 *               : C/C++ compiler package for the SuperH RISC engine family
38 *               :                               (Ver.9.01 Release01).
39 *   OS          : None
40 *   H/W Platform: M3A-HS87 (CPU board)
41 *   Description :
42 *****/
43 *   History     : Sep.10,2010 Ver.1.00.00
44 *"FILE COMMENT END"*****
45 #include <machine.h>
46 #include "iodefine.h"
47 #include "Flash_API_SH7280.h"
48

```

## 5.2 Sample Program Listing "main.c" (2/10)

```
49  /* ==== Macro definition ==== */
50  #define FLASH_PE_ENABLE      1  /* Flash program/erase enabled      */
51  #define FLASH_PE_DISABLE    0  /* Flash program/erase disabled    */
52  #define PROGRAM_SIZE        256 /* Flash programming size unit     */
53
54  #define CMD_GO               0x55 /* Flash memory programming/erasing start command */
55  #define CMD_READ             0xaa /* Flash memory reading command */
56  #define CMD_ERASE            0x77 /* Flash memory erasing command */
57  #define CMD_WRITE            0x88 /* Flash memory programming command */
58  #define CMD_WEND             0x99 /* Flash memory programming/erasing command */
59  #define RET_OK                0x00 /* Normal end */
60  #define RET_NG                0x01 /* Error end */
61  #define RET_REQ               0x11 /* Transmission request */
62
63  /* ==== Prototype declaration ==== */
64  void main(void);                /* main function */
65  void _section_init(void);       /* section initialization function */
66  void io_cpg_init(void);         /* FRQCR setting function */
67  int ocf_pe_chk(void);          /* Flash P/E check function */
68  void ocf_write(void);          /* Flash program/erase processing function */
69  void ocf_read(void);           /* Flash reading function */
70  void dummy_f(void);            /* Dummy interrupt function */
71  /* ---- External reference ---- */
72  extern void io_sci_init(void);
73  extern int io_sci_chk_rcv(void);
74  extern void io_sci_snd(unsigned char data);
75  extern void io_sci_rcv(unsigned char *data, unsigned long num);
76  extern void io_sci_stop(void);
77
78  /* ==== Global variable ==== */
79  #pragma section WriteDATA /* Program data buffer area */
80  unsigned char WriteBuff[PROGRAM_SIZE];
81  #pragma section
82
```

### 5.3 Sample Program Listing "main.c" (3/10)

```

83  /*"FUNC COMMENT"*****
84  * ID      :
85  * Outline : Sample program main
86  *-----
87  * Include :
88  *-----
89  * Declaration : void main(void);
90  *-----
91  * Description :
92  *-----
93  * Argument   : void
94  *-----
95  * Return Value : void
96  *-----
97  * Note       : None
98  *"FUNC COMMENT END"*****/
99  void main(void)
100 {
101     unsigned char RcvData;
102     int pe_ok;
103
104     /* ==== Initializes sections ==== */
105     _section_init();
106
107     /* ==== Initializes the FRQCR ==== */
108     io_cpg_init();
109
110     /* ==== Configures the SCI ==== */
111     io_sci_init();
112
113     /* ==== Checks the flash memory is program-/erase-enabled ==== */
114     do{
115         pe_ok = ocf_pe_chk();    /* FWE pin = High ? */
116     }while(pe_ok != FLASH_PE_ENABLE);
117
118     /* ==== Notifies the transmission request to the host computer ==== */
119     io_sci_snd(RET_REQ);
120
121     /* ==== Programs/erases the flash memory or reads the flash memory ==== */
122     while(1){
123         /* ---- Checks the user control command ---- */
124         if(io_sci_chk_rcv() != 0){
125             io_sci_rcv(&RcvData, 1);
126             if(RcvData == CMD_GO){
127                 ocf_write();    /* Programs or erases the flash memory */
128             }
129             else if(RcvData == CMD_READ){
130                 ocf_read();    /* Reads the flash memory */
131             }
132         }
133     }
134 }
135

```

## 5.4 Sample Program Listing "main.c" (4/10)

```
136 /*"FUNC COMMENT"*****
137 * ID      :
138 * Outline : Section initialization
139 *-----
140 * Include : <machine.h>
141 *-----
142 * Declaration : void _section_init(void);
143 *-----
144 * Description : Clears section B and program data buffer area to 0, and copies
145 *              : section D to the on-chip RAM (section R).
146 *-----
147 * Argument   : void
148 *-----
149 * Return Value : void
150 *-----
151 * Note       : None
152 *"FUNC COMMENT END"*****/
153 void _section_init(void)
154 {
155     unsigned char *src, *dst, *end;
156
157     /* Zero our all un-initialized (BSS) RAM data as specified by ANSI. */
158     src = (unsigned char *)(__sectop("B"));
159     end = (unsigned char *)(__secend("B"));
160     while(src < end){
161         *src++ = 0x00;
162     }
163
164     src = (unsigned char *)(__sectop("BWriteDATA"));
165     end = (unsigned char *)(__secend("BWriteDATA"));
166     while(src < end){
167         *src++ = 0x00;
168     }
169
170     /* Copy in our all initialized (DATA) RAM data as specified by ANSI. */
171     src = (unsigned char *)(__sectop("D"));
172     dst = (unsigned char *)(__sectop("R"));
173     end = (unsigned char *)(__secend("D"));
174     while(src < end){
175         *dst++ = *src++;
176     }
177 }
178
```

## 5.5 Sample Program Listing "main.c" (5/10)

```

179  /*"FUNC COMMENT"*****
180  * ID      :
181  * Outline : FRQCR initialization
182  * -----
183  * Include : <machine.h> and "iodefine.h"
184  * -----
185  * Declaration : void io_cpg_init(void);
186  * -----
187  * Description : Initializes the FRQCR register.
188  * -----
189  * Argument   : void
190  * -----
191  * Return Value : void
192  * -----
193  * Note       : None
194  * "FUNC COMMENT END"*****/
195  void io_cpg_init(void)
196  {
197      volatile unsigned short dummy;
198
199      WDT.WRITE.WTCSR = 0xa51e; /* WDT stop, WDT count clock: 1/4096 x P-clock */
200                          /* (Overflow cycle = 41.94 ms at P-clock 25 MHz) */
201      WDT.WRITE.WTCNT = 0x5ac2; /* WDT counter for 10 ms */
202      CPG.FRQCR.WORD = 0x0333; /* Clock-in = 12.5 MHz */
203                          /* I-clock = 25 MHz */
204                          /* B-clock = 25 MHz */
205                          /* P-clock = 25 MHz */
206                          /* -> (I : B : P) = (1/4 : 1/4 : 1/4) */
207      dummy = CPG.FRQCR.WORD; /* FRQCR readout */
208      /* ---- 64 NOPs for 32 x P-clock (I:P = 1:1) ---- */
209      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
210      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
211      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
212      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
213      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
214      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
215      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
216      nop(); nop(); nop(); nop(); nop(); nop(); nop(); nop();
217  }
218

```

## 5.6 Sample Program Listing "main.c" (6/10)

```

219  /*"FUNC COMMENT"*****
220  * ID      :
221  * Outline : Flash memory program-/erase-enabled state check
222  * -----
223  * Include : "iodefine.h"
224  * -----
225  * Declaration : int ocf_pe_chk(void);
226  * -----
227  * Description : Reads the FWE bit in the Flash code control and status register
228  *              : (FCCS) and returns the value.
229  * -----
230  * Argument   : void
231  * -----
232  * Return Value : 0 ; Flash memory is program-/erase-disabled
233  *              : 1 ; Flash memory is program-/erase-enabled
234  * -----
235  * Note       : None
236  * "FUNC COMMENT END"*****/
237  int ocf_pe_chk(void)
238  {
239      return FLASH.FCCS.BIT.FWE;
240  }
241
242  /*"FUNC COMMENT"*****
243  * ID      :
244  * Outline : Programming/erasing the flash memory
245  * -----
246  * Include : "Flash_API_SH7280.h"
247  * -----
248  * Declaration : void ocf_write(void);
249  * -----
250  * Description : Erases the program/erase destination block (other than EB0)
251  *              : which is specified by the host computer, and programs the
252  *              : specified size of data from the destination start address.
253  * -----
254  * Argument   : void
255  * -----
256  * Return Value : void
257  * -----
258  * Note       : None
259  * "FUNC COMMENT END"*****/
260  void ocf_write(void)
261  {
262      unsigned char error; /* Function return value */
263      unsigned char RcvData; /* Receive data */
264      unsigned char EraseBlkNum; /* Erase block number */
265      unsigned short EraseBlkSelect; /* Specified erase block number by bit field */
266      unsigned long WriteAddr; /* Start address to be programmed */
267      unsigned long WriteSize; /* Data size to be programmed */
268      unsigned long RcvSize; /* Receiving size for data to be programmed */
269      unsigned long i; /* Loop counter */
270

```

## 5.7 Sample Program Listing "main.c" (7/10)

```
271     /* ==== Transmission request ==== */
272     io_sci_snd(RET_REQ);
273
274     /* ==== Receives the flash memory erasing command ==== */
275     io_sci_rcv(&RcvData, 1);
276     if(RcvData != CMD_ERASE){ /* Received the command other than the CMD_ERASE? */
277         io_sci_snd(RET_NG); /* Error end */
278         while(1){
279             }
280     }
281
282     /* ==== Transmission request ==== */
283     io_sci_snd(RET_REQ);
284
285     /* ==== Receives the erase block number data ==== */
286     io_sci_rcv((unsigned char *)&EraseBlkSelect, 2);
287     if( (EraseBlkSelect == 0x0000) ||
288         ((EraseBlkSelect & 0x0001) != 0) ){
289         /* Block number is not specified or EBO is specified? */
290         io_sci_snd(RET_NG); /* Error end */
291         while(1){
292             }
293     }
294
295     /* ==== Erases the flash memory ==== */
296     EraseBlkNum = BLOCK_1;
297     do{
298         EraseBlkSelect >>= 1;
299         if((EraseBlkSelect & 0x0001) != 0){
300             /* ---- Sets the SCI in module standby ---- */
301             io_sci_stop();
302             /* ---- Erases a block ---- */
303             error = R_FlashErase((uint8_t)EraseBlkNum);
304             /* ---- Configures the SCI ---- */
305             io_sci_init();
306             if(error != 0){ /* Erase error occurred? */
307                 io_sci_snd(RET_NG); /* Error end */
308                 while(1){
309                     }
310             }
311         }
312     } while(EraseBlkNum++ <= BLOCK_15);
313
314     io_sci_snd(RET_OK); /* Normal end */
315
316
```

## 5.8 Sample Program Listing "main.c" (8/10)

```
317     /* ==== Programs the flash memory ==== */
318     while(1){
319         io_sci_rcv(&RcvData, 1);      /* Receives the user control command */
320         if(RcvData == CMD_WRITE){    /* Received the CMD_WRITE? */
321             io_sci_snd(RET_REQ);     /* Transmission request */
322         }
323         else if(RcvData == CMD_WEND){ /* Received the CMD_WEND? */
324             io_sci_snd(RET_OK);      /* Normal end */
325             break;
326         }
327         else{
328             io_sci_snd(RET_NG);      /* Error end */
329             while(1){
330                 }
331         }
332
333         /* ---- Receives the destination start address ---- */
334         io_sci_rcv((unsigned char *)&WriteAddr, 4);
335
336         /* ---- Receives the program data size ---- */
337         io_sci_rcv((unsigned char *)&WriteSize, 4);
338
339         while(WriteSize > 0){
340             io_sci_snd(RET_REQ);     /* Transmission request */
341
342             if(WriteSize > PROGRAM_SIZE){
343                 RcvSize = PROGRAM_SIZE;
344             }
345             else{
346                 RcvSize = WriteSize;
347                 for(i = RcvSize; i < PROGRAM_SIZE; i++){
348                     WriteBuff[i] = 0xff;
349                 }
350             }
351         }
```

## 5.9 Sample Program Listing "main.c" (9/10)

```

352     /* ---- Receives the program data ---- */
353     io_sci_rcv(WriteBuff, RcvSize); /* Stores the data in the program data buffer */
354
355     /* ---- Sets the SCI in module standby ---- */
356     io_sci_stop();
357     /* ---- Programs the flash memory ---- */
358     error = R_FlashWrite((uint32_t)WriteAddr, (uint32_t)WriteBuff, PROGRAM_SIZE);
359     /* ---- Configures the SCI ---- */
360     io_sci_init();
361     if(error != 0){ /* Program error occurred? */
362         io_sci_snd(error); /* Error end */
363         while(1){
364             }
365     }
366
367     WriteAddr += PROGRAM_SIZE;
368     WriteSize -= RcvSize;
369 }
370 io_sci_snd(RET_OK); /* Normal end */
371 }
372
373 }
374
375 /*"FUNC COMMENT"*****
376 * ID :
377 * Outline : Reading the flash memory
378 *-----
379 * Include :
380 *-----
381 * Declaration : void ocf_read(void);
382 *-----
383 * Description : Reads the specified size of data from the read destination
384 * : start address and transmits the data to the host computer.
385 *-----
386 * Argument : void
387 *-----
388 * Return Value : void
389 *-----
390 * Note : None
391 *"FUNC COMMENT END"*****/
392 void ocf_read(void)
393 {
394     unsigned char *ReadData; /* Pointer for readout data */
395     unsigned long ReadAddr; /* Start address to be read */
396     unsigned long ReadSize; /* Reading size */
397     unsigned long i; /* Loop counter */
398
399     /* ==== Transmission request ==== */
400     io_sci_snd(RET_REQ);
401

```

## 5.10 Sample Program Listing "main.c" (10/10)

```

402     /* ==== Receives the read destination start address ==== */
403     io_sci_rcv((unsigned char *)&ReadAddr, 4);
404     if(ReadAddr >= 0x00100000){
405         /* Specified the address other than the user MAT? */
406         io_sci_snd(RET_NG);           /* Error end */
407         while(1){
408             }
409     }
410
411     /* ==== Receives the read data size ==== */
412     io_sci_rcv((unsigned char *)&ReadSize, 4);
413
414     /* ==== Transmits the data which is read from ROM ==== */
415     ReadData = (unsigned char *)ReadAddr;
416     for(i = 0; i < ReadSize; i++){
417         io_sci_snd(*ReadData++);
418     }
419 }
420
421 /*"FUNC COMMENT"*****
422 * ID           :
423 * Outline      : Interrupt handling (dummy function).
424 *-----
425 * Include      :
426 *-----
427 * Declaration  : void dummy_f(void);
428 *-----
429 * Description  :
430 *-----
431 * Argument     : void
432 *-----
433 * Return Value : void
434 *-----
435 * Note        : None
436 *"FUNC COMMENT END"*****/
437 #pragma interrupt dummy_f
438 void dummy_f(void)
439 {
440     while(1){
441         /* Infinite loop */
442     }
443 }
444
445 /* End of File */

```

## 6. References

- Software Manual  
SH-2A/SH2A-FPU Software Manual Rev. 3.00  
The latest version of the software manual can be downloaded from the Renesas Electronics website.
- Hardware Manual  
SH7280 Group Hardware Manual Rev. 2.00  
The latest version of the hardware manual can be downloaded from the Renesas Electronics website.
- Technical update  
Prohibition of Interrupts during Programming/Erasing in User Program Mode (TN-SH7-A657A/E)

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## Revision Record

Rev.	Date	Description	
		Page	Summary
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## General Precautions in the Handling of MPU/MCU Products

The following usage notes are applicable to all MPU/MCU products from Renesas. For detailed usage notes on the products covered by this manual, refer to the relevant sections of the manual. If the descriptions under General Precautions in the Handling of MPU/MCU Products and in the body of the manual differ from each other, the description in the body of the manual takes precedence.

### 1. Handling of Unused Pins

Handle unused pins in accord with the directions given under Handling of Unused Pins in the manual.

- The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible. Unused pins should be handled as described under Handling of Unused Pins in the manual.

### 2. Processing at Power-on

The state of the product is undefined at the moment when power is supplied.

- The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the moment when power is supplied.

In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the moment when power is supplied until the reset process is completed.

In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the moment when power is supplied until the power reaches the level at which resetting has been specified.

### 3. Prohibition of Access to Reserved Addresses

Access to reserved addresses is prohibited.

- The reserved addresses are provided for the possible future expansion of functions. Do not access these addresses; the correct operation of LSI is not guaranteed if they are accessed.

### 4. Clock Signals

After applying a reset, only release the reset line after the operating clock signal has become stable.

When switching the clock signal during program execution, wait until the target clock signal has stabilized.

- When the clock signal is generated with an external resonator (or from an external oscillator) during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Moreover, when switching to a clock signal produced with an external resonator (or by an external oscillator) while program execution is in progress, wait until the target clock signal is stable.

### 5. Differences between Products

Before changing from one product to another, i.e. to one with a different type number, confirm that the change will not lead to problems.

- The characteristics of MPU/MCU in the same group but having different type numbers may differ because of the differences in internal memory capacity and layout pattern. When changing to products of different type numbers, implement a system-evaluation test for each of the products.

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Tel: +1-408-588-6000, Fax: +1-408-588-6130

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1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada  
Tel: +1-905-898-5441, Fax: +1-905-898-3220

#### Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.  
Tel: +44-1628-585-100, Fax: +44-1628-585-900

#### Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

#### Renesas Electronics (China) Co., Ltd.

7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

#### Renesas Electronics (Shanghai) Co., Ltd.

Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China  
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

#### Renesas Electronics Hong Kong Limited

Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2886-9318, Fax: +852-2886-9022/9044

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7F, No. 363 Fu Shing North Road Taipei, Taiwan, R.O.C.  
Tel: +886-2-8175-9600, Fax: +886-2-8175-9670

#### Renesas Electronics Singapore Pte. Ltd.

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Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

#### Renesas Electronics Korea Co., Ltd.

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